

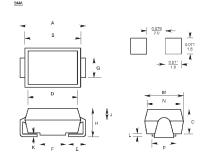
# **SKN7 THRU SKN9**

### SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

**Reverse Voltage -** 20 to 40 Volts **Forward Current -** 1.0 Ampere

#### **Features**

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guardring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250 ℃/10 seconds, 2.8mm lead length



#### **Mechanical Data**

• Case: SMA molded plastic body

• Polarity: Color band denotes cathode end

Mounting Position: AnyWeight: 0.004 ounce, 0.11 gram

D IM E N S IO N S								
DIM	inches		m m		Note			
	M in .	Max.	M in .	Max.	Note			
A	0.216	0.226	5.48	5 . 7 4				
В	0.176	0.182	4.48	4 . 6 3				
С	0.094	0.100	2.40	2.55				
D	0.170	0.176	4.33	4 . 4 8				
E	0.039	0.055	1.00	1.40				
F	0.080	0.081	2.03	2.07				
G	0.068	0.083	1.72	2.10				
н	0.112	0.118	2.85	3.00				
J	0.057		1.44					
K		0.018	-	0.45				
L	0.016		0.40					
М	0.109	0.115	2.77	2.93				
N	0.105	0.107	2 . 6 7	2.73				
P	0.078	0.081	2.00	2.05				

# **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

	Symbols	SKN7	SKN8	SKN9	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	Volts
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	Volts
Maximum non-repetitive peak reverse voltage	V <sub>RSM</sub>	24	36	48	Volts
Maximum average forward rectified current 2.8mm lead length at T $_{\rm L}$ =90 $^{\circ}{\rm C}$	I <sub>(AV)</sub>	1.0			Amp
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method) at $\rm T_L$ =70 $^{\circ}\rm C$	I <sub>FSM</sub>	25.0			Amps
Maximum instantaneous forward voltage at 1.0A (Note 1) Maximum instantaneous forward voltage at 3.1A (Note 1)	V <sub>F</sub>	0.450 0.750	0.550 0.875	0.600 0.900	Volts Volts
Maximum instantaneous reverse current T=25 $^{\circ}$ C at rated DC blocking voltage T_A=110 $^{\circ}$ C	I <sub>R</sub>	1.0 10.0			mA
Typical junction capacitance (Note 3)	C <sub>J</sub>	110.0			ρF
Typical thermal resistance (Note 2)	R <sub>⊕JA</sub> R <sub>⊕JL</sub>	50.0 15.0			°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +125			${\mathbb C}$

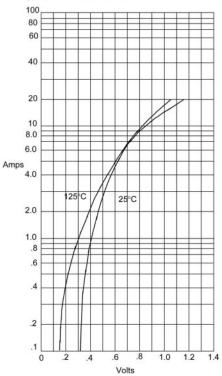
#### Notes

- (1) Pulse test: 300uS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to lead, and/or to ambient P.C.B. mounted with 2.8mm lead length with 1.5X1.5" (38X38mm) copper pads
- (3) Measured at 1.0MHz and applied reverse voltage of 4.0 volts

### **RATINGS AND CHARACTERISTIC CURVES**

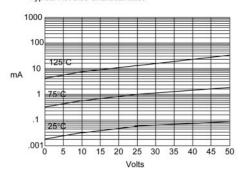
SKN7

Figure 1 Typical Forward Characteristics



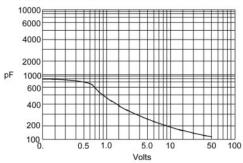
Instantaneous Forward Current - Amperesversus Instantaneous Forward Voltage - Volts

Figure 2 Typical Reverse Characteristics



Typical Reverse Current - mAversus Reverse Voltage - Volts

Figure 3 Typical Junction Capacitance



Junction Capacitance - pF versus Reverse Voltage - Volts

Figure 4 New SMA Assembly

Round Lead Process

# **RATINGS AND CHARACTERISTIC CURVES**

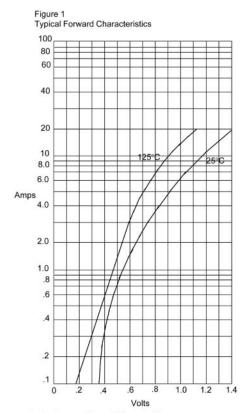
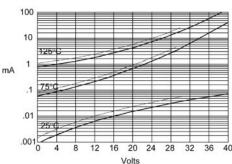


Figure 3 Typical Junction Capacitance 1000 600 400 200 100 60 40 20 100 0.5 1.0 5.0 10 50 100 Volts Junction Capacitance - pF versus Reverse Voltage - Volts

Figure 4 New SMA Assembly Round Lead Process

Instantaneous Forward Current - Amperesversus Instantaneous Forward Voltage - Volts

Figure 2 Typical Reverse Characteristics



Typical Reverse Current - mAversus Reverse Voltage - Volts

SKN8

SKN9